

HIGH CURRENT SWITCHING APPLICATIONS.

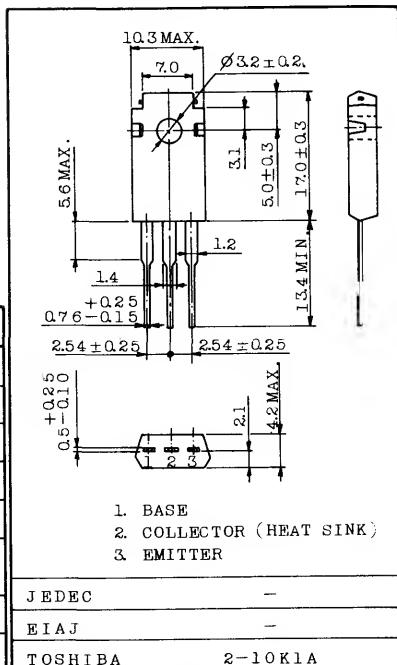
INDUSTRIAL APPLICATIONS
Unit in mm

FEATURES:

- . Low Collector Saturation Voltage
: $V_{CE(sat)}=0.4V$ (Max.) (at $I_C=3A$)
- . High Speed Switching Time : $t_{stg}=1.0\mu s$ (Typ.)
- . Complementary to 2SA1279

MAXIMUM RATINGS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	5	A
Base Current	I_B	1	A
Collector Power Dissipation ($T_c=25^\circ C$)	P_C	25	W
Junction Temperature	T_j	150	$^\circ C$
Storage Temperature Range	T_{stg}	-55 ~ 150	$^\circ C$



Weight : 2.0g

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=50V, I_E=0$	-	-	1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	-	-	1	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA, I_B=0$	50	-	-	V
DC Current Gain	$h_{FE}(1)$ (Note)	$V_{CE}=1V, I_C=1A$	70	-	240	
	$h_{FE}(2)$	$V_{CE}=1V, I_C=3A$	30	-	-	
Saturation Voltage	Collector-Emitter	$V_{CE(sat)}$	$I_C=3A, I_B=0.15A$	-	0.2	0.4
	Base-Emitter	$V_{BE(sat)}$	$I_C=3A, I_B=0.15A$	-	0.9	1.2
Transition Frequency	f_T	$V_{CE}=4V, I_C=1A$	-	120	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	80	-	MHz
Switching Time	Turn-on Time	t_{on}	$20\mu s$ I_{B1} INPUT I_{B2} OUTPUT $I_{B1} = -I_{B2} = 0.15A$	-	0.1	-
	Storage Time	t_{stg}	I_{B1} INPUT I_{B2} OUTPUT $I_{B1} = -I_{B2} = 0.15A$ DUTY CYCLE $\leq 1\%$	-	1.0	-
	Fall Time	t_f	$V_{CC}=30V$	-	0.1	-

Note : $h_{FE}(1)$ Classification 0 : 70 ~ 140, Y : 120 ~ 240

